

Octal Buffer/Line Driver with 3-STATE Outputs

74AC244, 74ACT244

General Description

The AC/ACT244 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter/receiver which provides improved PC board density.

Features

- $\bullet~I_{CC}$ and I_{OZ} Reduced by 50%
- 3-STATE Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- ACT244 has TTL-Compatible Inputs

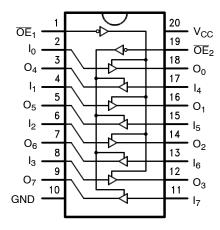


Figure 1. Connection Diagram

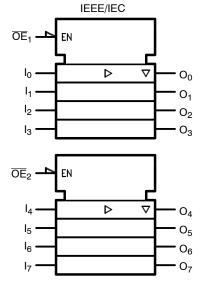


Figure 2. Logic Symbol





SOIC-20 WB CASE 751D-05



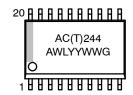
TSSOP-20 WB CASE 948E



TSSOP20, 4.4 x 6.5 CASE 948AQ-01

MARKING DIAGRAMS

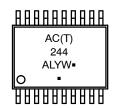
SOIC-20



AC244, ACT244 = Specific Device Code A = Assembly Location WL = Wafer Lot

YY = Year WW = Work Week G = Pb-Free Package

TSSOP-20



AC244, ACT244 = Specific Device Code
A = Assembly Location
L = Wafer Lot

Y = Year W = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

PIN DESCRIPTION

Pin Name	Description			
OE₁, OE₂ 3-STATE Output Enable Inputs				
I ₀ -I ₇	Inputs			
O ₀ -O ₇	Outputs			

TRUTH TABLE

Inp	uts	Outputs			
ŌĒ ₁	In	(Pins 12, 14, 16, 18)			
L	L	L			
L	Н	Н			
Н	Х	Z			

NOTE: X = Immaterial, Z = High Impedance

TRUTH TABLE (continued)

Inp	uts	Outputs
ŌĒ₂	In	(Pins 3, 5, 7, 9)
L	L	L
L	Н	Н
Н	Х	Z

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{CC}	−0.5 to +7.0	V
DC Input Diode Current VI = -0.5 V	I _{IK}	-20	mA
V _I = V _{CC} + 0.5	7	+20	
DC Input Voltage	VI	-0.5 to V _{CC} + 0.5	V
DC Output Diode Current $V_O = -0.5 \text{ V}$	Гок	-20	mA
$V_{I} = V_{CC} + 0.5 V$	7	+20	
DC Output Voltage	V _O	-0.5 to V _{CC} + 0.5	V
DC Output Source or Sink Current	I _O	±50	mA
DC V _{CC} or Ground Current per Output Pin	I _{CC} or I _{GND}	±50	mA
Storage Temperature	T _{STG}	−65 to +150	°C
Junction Temperature	TJ	140	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Rating	Unit
Supply Voltage AC	V _{CC}	2.0 to 6.0	V
ACT		4.5 to 5.5	
Input Voltage	V _I	0 to V _{CC}	V
Output Voltage	V _O	0 to V _{CC}	V
Operating Temperature	T _A	-40 to +85	°C
Minimum Input Edge Rate, AC Devices: V _{IN} from 30% to 70% of V _{CC} , V _{CC} @ 3.3 V, 4.5 V, 5.5 V	ΔV / Δt	125	mV/ns
Minimum Input Edge Rate, ACT Devices: V _{IN} from 0.8 V to 2.0 V, V _{CC} @ 4.5 V, 5.5 V	ΔV / Δt	125	mV/ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS FOR AC

				T _A = -	+25°C	T _A = -55°C to +125°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур		Guaranteed L	imits	Unit
V _{IH}	Minimum HIGH Level	3.0	V _{OUT} = 0.1 V or	1.5	2.1	2.1	2.1	V
	Input Voltage	4.5	V _{CC} – 0.1 V	2.25	3.15	3.15	3.15	
		5.5	1	2.75	3.85	3.85	3.85	
V _{IL}	Maximum LOW Level	3.0	V _{OUT} = 0.1 V or	1.5	0.9	0.9	0.9	V
	Input Voltage	4.5	V _{CC} – 0.1 V	2.25	1.35	1.35	1.35	
		5.5	1	2.75	1.65	1.65	1.65	
V _{OH}	Minimum HIGH Level	3.0	I _{OUT} = -50 μA	2.99	2.9	2.9	2.9	V
	Output Voltage	4.5	1	4.49	4.4	4.4	4.4	
		5.5	1	5.49	5.4	5.4	5.4	
		3.0	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = 12$ mA		2.56	2.40	2.46	
		4.5	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = 24$ mA		3.86	3.70	3.76	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = 24 \text{ mA (Note 1)}$		4.86	4.70	4.76	
V _{OL}	Maximum LOW Level	3.0	I _{OUT} = 50 μA	0.002	0.1	0.1	0.1	V
	Output Voltage	4.5	1	0.001	0.1	0.1	0.1	
		5.5	1	0.001	0.1	0.1	0.1	
		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 12 \text{ mA}$		0.36	0.50	0.44	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{ mA}$		0.36	0.50	0.44	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{ mA (Note 1)}$		0.36	0.50	0.44	
I _{IN} (Note 2)	Maximum Input Leakage Current	5.5	$V_I = V_{CC}$, GND		±0.1	±1.0	±1.0	μΑ
l _{OZ}	Maximum 3-STATE Leakage Current	5.5	$ \begin{aligned} &V_{I} \text{ (OE)} = V_{IL}, V_{IH}; \\ &V_{I} = V_{CC}, V_{GND}; \\ &V_{O} = V_{CC}, \text{ GND} \end{aligned} $		±0.25	±5.0	±2.5	μΑ
I _{OLD}	Minimum Dynamic	5.5	V _{OLD} = 1.65 V Max.			50	75	mA
I _{OHD}	Output Current (Note 3)	5.5	V _{OHD} = 3.85 V Min.			-50	-75	mA
I _{CC} (Note 2)	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND		4.0	80.0	40.0	μΑ

All outputs loaded; thresholds on input associated with output under test.
 I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.
 Maximum test duration 2.0 ms, one output loaded at a time.

DC ELECTRICAL CHARACTERISTICS FOR ACT

				T _A = -	+25°C	T _A = -55°C to +125°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур		Guaranteed L	imits	Unit
V _{IH}	Minimum HIGH Level	4.5	V _{OUT} = 0.1 V or	1.5	2.0	2.0	2.0	V
	Input Voltage	5.5	V _{CC} – 0.1 V	1.5	2.0	2.0	2.0	
V _{IL}	Maximum LOW Level	4.5	V _{OUT} = 0.1 V or	1.5	0.8	0.8	0.8	V
	Input Voltage	5.5	V _{CC} – 0.1 V	1.5	0.8	0.8	0.8	
V _{OH}	Minimum HIGH Level	4.5	I _{OUT} = -50 μA	4.49	4.4	4.4	4.4	V
	Output Voltage	5.5		5.49	5.4	5.4	5.4	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = 24 \text{ mA}$		3.86	3.70	3.76	
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = 24 mA (Note 4)		4.86	4.70	4.76	
V _{OL}	Maximum LOW Level Output Voltage	4.5	I _{OUT} = 50 μA	0.001	0.1	0.1	0.1	V
		5.5	1	0.001	0.1	0.1	0.1	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{ mA}$		0.36	0.50	0.44	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{ mA (Note 4)}$		0.36	0.50	0.44	
I _{IN}	Maximum Input Leakage Current	5.5	$V_I = V_{CC}$, GND		±0.1	±1.0	±1.0	μΑ
I _{OZ}	Maximum 3-STATE Leakage Current	5.5	$V_I = V_{IL}, V_{IH};$ $V_O = V_{CC}, GND$		±0.25	±5.0	±2.5	μΑ
I _{CCT}	Maximum I _{CC} /Input	5.5	V _I = V _{CC} - 2.1 V	0.6		1.6	1.5	mA
I _{OLD}	Minimum Dynamic	5.5	V _{OLD} = 1.65 V Max.			50	75	mA
I _{OHD}	Output Current (Note 5)	5.5	V _{OHD} = 3.85 V Min.			-50	-75	mA
Icc	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND		4.0	80.0	40.0	μΑ

^{4.} All outputs loaded; thresholds on input associated with output under test.5. Maximum test duration 2.0 ms, one output loaded at a time.

AC ELECTRICAL CHARACTERISTICS FOR AC

		V _{CC} (V)	T _A = +25°C, C _L = 50 pF		+12	55°C to 5°C 50 pF	+85	10°C to 5°C 50 pF		
Symbol	Parameter	(Note 6)	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay,	3.3	2.0	6.5	9.0	1.0	12.5	1.5	10.0	ns
	Data to Output	5.0	1.5	5.0	7.0	1.0	9.5	1.0	7.5	
t _{PHL}	Propagation Delay,	3.3	2.0	6.5	9.0	1.0	12.0	2.0	10.0	ns
	Data to Output	5.0	1.5	5.0	7.0	1.0	9.0	1.0	7.5	
t _{PZH}	Output Enable Time	3.3	2.0	6.0	10.5	1.0	11.5	1.5	11.0	ns
		5.0	1.5	5.0	7.0	1.0	9.0	1.5	8.0	
t _{PZL}	Output Enable Time	3.3	2.5	7.5	10.0	1.0	13.0	2.0	11.0	ns
		5.0	1.5	5.5	8.0	1.0	10.5	1.5	8.5	
t _{PHZ}	Output Disable Time	3.3	3.0	7.0	10.0	1.0	12.5	1.5	10.5	ns
		5.0	2.5	6.5	9.0	1.0	10.5	1.0	9.5	
t _{PLZ}	Output Disable Time	3.3	2.5	7.5	10.5	1.0	13.0	2.5	11.5	ns
		5.0	2.0	6.5	9.0	1.0	11.0	2.0	9.5	

^{6.} Voltage range 3.3 is 3.3 V \pm 0.3 V. Voltage range 5.0 is 5.0 V \pm 0.5 V.

AC ELECTRICAL CHARACTERISTICS FOR ACT

		V _{CC} (V)	T _A = +25°C, C _L = 50 pF		C ₁ = 50 pF		T _A = -40°C to +85°C C _L = 50 pF			
Symbol	Parameter	(Note 7)	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay, Data to Output	5.0	2.0	6.5	9.0	1.0	10.0	1.5	10.0	ns
t _{PHL}	Propagation Delay, Data to Output	5.0	2.0	7.0	9.0	1.0	10.0	1.5	10.0	ns
t _{PZH}	Output Enable Time	5.0	1.5	6.0	8.5	1.0	9.5	1.0	9.5	ns
t _{PZL}	Output Enable Time	5.0	2.0	7.0	9.5	1.0	11.0	1.5	10.5	ns
t _{PHZ}	Output Disable Time	5.0	2.0	7.0	9.5	1.0	11.0	1.5	10.5	ns
t _{PLZ}	Output Disable Time	5.0	2.5	7.5	10.0	1.0	11.5	2.0	10.5	ns

^{7.} Voltage range 5.0 is 5.0 V \pm 0.5 V.

CAPACITANCE

	Symbol	Parameter	Conditions	Тур	Unit
Ī	C _{IN} Input Capacitance		V _{CC} = OPEN	4.5	pF
I	C_{PD}	Power Dissipation Capacitance	V _{CC} = 5.0 V	45.0	pF

ORDERING INFORMATION

Order Number	Package	Shipping [†] (Qty / Packing)
74AC244SC	SOIC-20W (Pb-Free)	38 / Tube
74AC244SCX	SOIC-20W (Pb-Free)	1000 / Tape & Reel
74AC244MTC	TSSOP-20 (Pb-Free)	75 / Tube
74AC244MTCX	TSSOP-20 (Pb-Free)	2500 / Tape & Reel
74ACT244SC	SOIC-20W (Pb-Free)	38 / Tube
74ACT244SCX	SOIC-20W (Pb-Free)	1000 / Tape & Reel
74ACT244MTC	TSSOP-20 (Pb-Free)	75 / Tube
74ACT244MTCX	TSSOP-20 (Pb-Free)	2500 / Tape & Reel

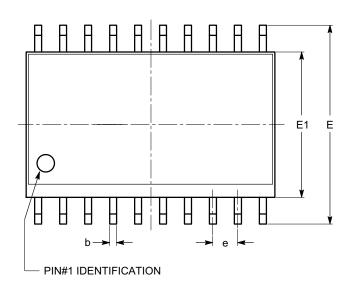
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

NOTE: All packages are lead free per JEDEC: J-STD-020B standard.



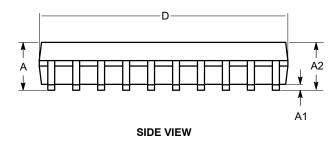
SOIC-20, 300 mils CASE 751BJ-01 ISSUE O

DATE 19 DEC 2008



SYMBOL	MIN	NOM	MAX
А	2.36	2.49	2.64
A1	0.10		0.30
A2	2.05		2.55
b	0.31	0.41	0.51
С	0.20	0.27	0.33
D	12.60	12.80	13.00
Е	10.01	10.30	10.64
E1	7.40	7.50	7.60
е		1.27 BSC	
h	0.25		0.75
L	0.40	0.81	1.27
θ	0°		8°
θ1	5°		15°

TOP VIEW



θ1 θ1 c

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-013.

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DESCRIPTION:	SOIC-20, 300 MILS		PAGE 1 OF 1

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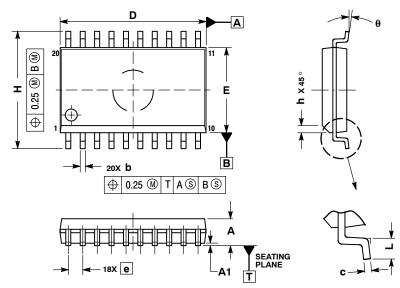




SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015

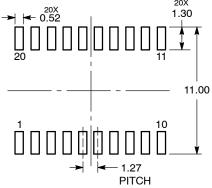
SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

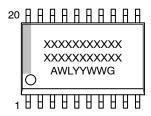
	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
b	0.35	0.49		
С	0.23	0.32		
D	12.65	12.95		
E	7.40	7.60		
е	1.27 BSC			
Н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
A	0 °	7 °		

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

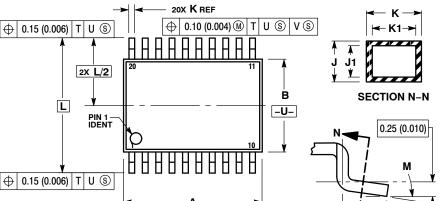
0.100 (0.004)

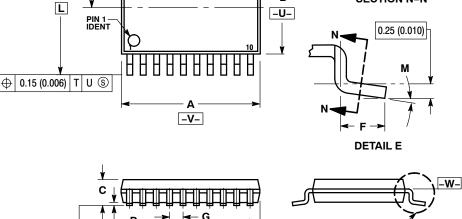
-T- SEATING



TSSOP-20 WB CASE 948E ISSUE D

DATE 17 FEB 2016





NOTES:

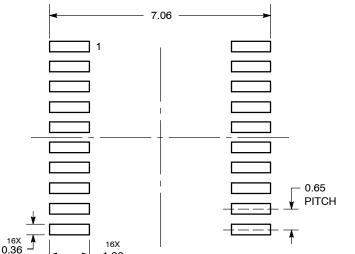
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
- (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
Ĺ	6.40 BSC		0.252	BSC
M	0°	8°	0°	8°

GENERIC SOLDERING FOOTPRINT MARKING DIAGRAM*

DETAIL E



<u>aaaaaaaa</u>	<u> </u>
XXXX	
XXXX	
ALYW ■	
0 •	
	H

= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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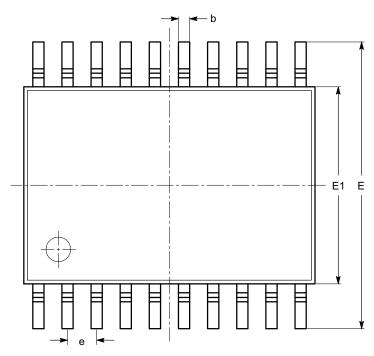
DIMENSIONS: MILLIMETERS

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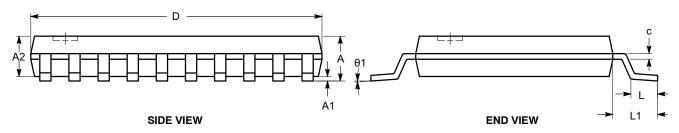
TSSOP20, 4.4x6.5CASE 948AQ-01
ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
Α			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

TOP VIEW



Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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